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Corbino experimental set-up for Cooper pair mass spectroscopy and determination of mobility in normal phase

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We are suggesting an electronic method for Cooper pair mass spectroscopy of thin superconducting films. The method can be applied, for example, for 100 nm thin high-T_c films grown on insulator substrate 10 mm×10 mm. In Corbino geometry two Ohmic contacts have to be made on the film evaporating Ag or using silver paste: one circle with radius r_a (1) and a ring electrode with internal radius r_b (2). In the in-between space (r_a,r_b) a ring electrode from mylar assures a capacitive connection between the superconducting layer and the metallized surface (3) of the mylar. In such a way we have an field effect transistor (FET) type structure with a circular gate. When at low enough temperatures $T \ll T_c$ an AC current with frequency ω is applied between the circle source (1) and the ring-shaped drain (2) an AC Bernoulli voltage with double frequency $2f$ appears between the gate (3) and the source (1). The $2f$ signal depends on Cooper pair effective mass and its systematic investigation gives a Cooper pair mass spectroscopy. In the normal phase $2f$ gives logarithmic derivative of the density of states (DOS) with respect of Fermi energy. Applying a gate voltage in the same structure gives the mobility of the normal phase.

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In spite of the intensive development of physics of superconductivity and especially high-T_c superconductivity in during the last two decades the effective mass of Cooper pairs remains an almost inaccessible parameter.[1] The purpose of the preset work is to suggest the simplest electronic method for determination of the effective mass which does not require patterning of the film or preparing of superconducting micro-structures. The method can be applied for bare superconducting films; imagine for example a 100 nm cuprate superconductor grown on a 10 mm×10 mm perovskite substrate. The method we suggest is based on the Bernoulli effect.

The main detail of the suggested experimental set-up is a ring electrode (3) from mylar affixed on the clean superconductor surface. The polymer insulator layer of the mylar contacts to the superconducting surface while the gate electrode is affixed on the top of the metallized layer of the mylar. In such a way we have a metal-insulator-superconductor (MIS) type structure. The ring has inner radius r_a and outer radius r_b. Using a silver paste or evaporating silver, a circular Ohmic contact (1) with radius r_a is made in the center. Another Ohmic probe (2) with inner radius r_b surrounds the capacitor ring. The Ohmic contacts (1) and (2) are as source and drain probes of a field-effect transistor (FET) type structure, while the metallized layer (3) plays the role of the gate. Thus we have a superconductor FET-type device in circular Corbino geometry.

When a source-drain current

$$I_{SD}(t) = I_0 \cos \omega t \tag{1}$$

is applied between source (1) and drain (2) an almost homogeneous current density is created

$$j = \frac{I_{SD}}{2\pi r d_{\mathrm{film}}} = e^* n v \tag{2}$$

in the superconductor layer. We suppose that the thickness of the film is smaller than London penetration depth λ. For simplicity we consider low enough temperatures $T \ll T_c$ when all charge carriers are superfluid and the penetration depth is expressed by the effective mass of Cooper pairs m^*, its charge e^* and volume density n

$$\frac{1}{\lambda^2(T)} = \frac{e^{*2} n}{m^* c^2 \epsilon_0}; \quad \frac{1}{c^2 \epsilon_0} = \mu_0 = 4\pi * 10^{-7}. \tag{3}$$

For dissipation free low frequency current, the constancy of the electrochemical potential in the bulk of the superconductor for $T \ll T_c$ gives Bernoulli theorem

$$\frac{1}{2} m^* v^2 + e^* \phi(r) = const. \tag{4}$$

The radius dependent electric potential $\phi(r)$ creates the Bernoulli voltage

$$U_b(t) = -\frac{1}{2} \frac{m^*}{e^*} \langle v^2 \rangle. \tag{5}$$

Where averaging is on the superconducting surface of the plane capacitor.

For this averaging we have to calculate

$$\langle \frac{1}{r^2} \rangle = \frac{\int_{r_a}^{r_b} \frac{1}{r^2} \mathrm{d}\pi r^2}{\int_{r_a}^{r_b} 1 \, \mathrm{d}\pi r^2} = \frac{\ln(r_b^2/r_a^2)}{r_b^2 - r_a^2}. \tag{6}$$

And for Bernoulli voltage measured at second harmonics

$$U(t) = U_{2f} \cos 2\omega t \tag{7}$$

we obtain

$$U_{2f} = -\frac{\ln(r_b/r_a)}{4\pi(r_b^2 - r_a^2)d_{\mathrm{film}}}\frac{\lambda^2(0)}{\lambda^2(T)}\left(\frac{\lambda^2(0)}{\epsilon_0 c^2}\right)^2 \frac{e^*}{m^*}\, I_0^2. \qquad (8)$$

The plot U_{2f} versus I_0^2 determines m^*. The temperature dependance $\lambda^2(0)/\lambda^2(T)$ is described in Refs. 1,2. The Bernoulli potential as current induced contact potential difference[2] has to be measured as source (1) – gate (3) signal. Additional possibilities are: for a second point to be used not the central ring but some Ohmic connection to certain of the corners of the films where the current density is very low or a second capacitor ring (4) to be affixed surrounding the other Ohmic ring. If the capacitance of the mylar ring is not much smaller than the internal capacitance of the Lock-in preamplifier we have to take into account the corresponding decrease of the signal. The evaluations of the magnitude for cuprate films gives that Bernoulli potential can be of order of μV and the experiment is actually very simple.

Few words we have to add for the normal phase. Above T_c the normal current oscillations in this case create the oscillations of the temperature with frequency $2f$. Second harmonic oscillations of the work function $W(t)$ give the logarithmic derivative of the density of states.[3]

In such a way the suggested experimental set-up can give important fundamental knowledge for the properties of the investigated materials. It is a pity that up to now we have only one reliable determination of effective mass of Cooper pairs based actually on a similar MIS structure investigations.[4,5] If silver paste is used for making of Ohmic contact they can be often cleaned by acetone and the film can be reused for other studies.

Every Lock-in has sensitivity of μV and possibility of second harmonic detection. That is why we conclude that the suggested method for mass spectroscopy can be realized in every laboratory involved with preparation of high-T_c films, and in every low temperature physics laboratory effective mass of Cooper pairs m^* can be measured. If the gate electrodes are used not for the detection but to apply an external voltage, a lot of new possibilities for fundamental research are open. The gate voltage induces external charge density on the surface of the superconductor

$$D_z = \epsilon_0\epsilon_r E_z; \quad E_z = U_{\mathrm{gate}}/d_{\mathrm{ins}}. \qquad (9)$$

As it is typical for physics of FET these surface charges change the two dimensional conductivity which in Corbino geometry is radial

$$j_r^{(2D)} = (en_{\mathrm{normal}}d_{\mathrm{film}} + D_z)\frac{e\tau}{m}E_r \qquad (10)$$

Investigation of the SD current $j_r^{(2D)}$ influenced by the gate voltage can give an independent method for determination of mobility $e\tau/m$ of the normal phase and charge carrier density.

Another possibility to determination of effective mass of Cooper pairs is to use electrostatic doping of the superconducting phase and its influence on the eddy currents created by a DC coil. Perhaps it is a more convenient procedure than the original method applied by Fiory and al.[5]

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